MMB以3700上東西南 MPN3700

High Voltage Silicon Pin Diodes

These devices are designed primarily for VHF band switching applications but are also suitable for use in general-purpose switching circuits. They are supplied in a cost-effective plastic package for economical, high-volume consumer and industrial requirements. They are also available in surface mount.

Features

- Long Reverse Recovery Time $t_{rr} = 300 \text{ ns (Typ)}$
- Rugged PIN Structure Coupled with Wirebond Construction for Optimum Reliability
- Low Series Resistance @ 100 MHz $R_S = 0.7 \Omega$ (Typ) @ $I_F = 10 \text{ mAdc}$
- Reverse Breakdown Voltage = 200 V (Min)
- Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V_{R}	20	Vdc
Forward Power Dissipation @ T _A = 25°C MMBV3700LT1 Derate above 25°C	P _D	200 2.8	mW mW/°C
Forward Power Dissipation @ T _A = 25°C MPN3700 Derate above 25°C	P _D	280 2.8	mW mW/°C
Junction Temperature	TJ	+125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



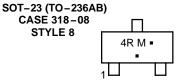
ON Semiconductor®

http://onsemi.com



MARKING DIAGRAM





4R = Specific Device Code

M = Date Code*

■ = Pb–Free Package

(Note: Microdot may be in either location)

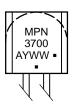
*Date Code orientation and/or overbar may vary depending upon manufacturing location.



MARKING DIAGRAM



TO-92 (TO-226AC) CASE 182-06 STYLE 1



MPN = Device Code 3700 = Specific Device A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

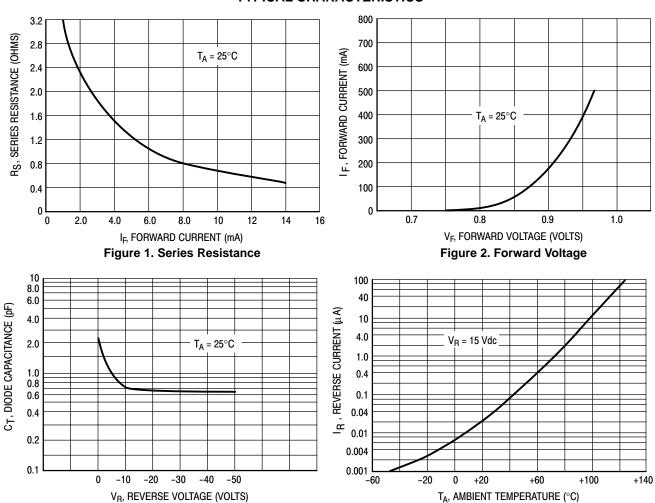
See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MMBV3700LT1, MPN3700

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μAdc)	V _{(BR)R}	200	-	_	Vdc
Diode Capacitance (V _R = 20 Vdc, f = 1.0 MHz)	C _T	-	-	1.0	pF
Series Resistance (Figure 5) (I _F = 10 mAdc)	R _S	-	0.7	1.0	Ω
Reverse Leakage Current (V _R = 150 Vdc)	I _R	-	-	0.1	μAdc
Reverse Recovery Time (I _F = I _R = 10 mAdc)	t _{rr}	-	300	_	ns

TYPICAL CHARACTERISTICS



ORDERING INFORMATION

Figure 3. Diode Capacitance

Device	Package	Shipping [†]			
MMBV3700LT1	SOT-23	3000 / Tape & Reel			
MMBV3700LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel			
MPN3700	TO-92	1000 Units / Bulk			
MPN3700G	TO-92 (Pb-Free)	1000 Units / Bulk			

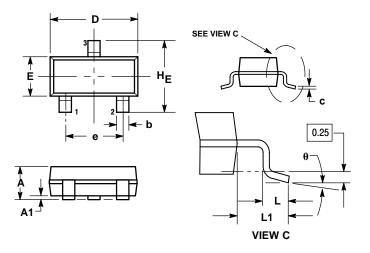
Figure 4. Leakage Current

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

查询"MMBV3700LT1G"供应商

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**

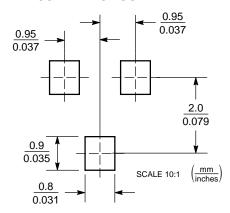


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- BASE MATERIAL.
 4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
C	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	

- STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE

SOLDERING FOOTPRINT*



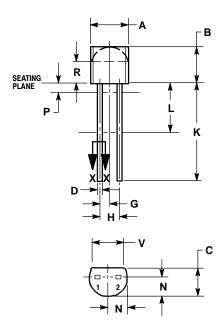
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MMBV3700LT1, MPN3700

查询"MMBV3700LT1G"供应商

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 182-06 ISSUE AL





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 FM 1982
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND ZONE R IS UNCONTROLLED.
- 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.21	
В	0.170	0.210	4.32	5.33	
C	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.050 BSC		1.27 BSC		
Н	0.100	BSC	2.54 BSC		
7	0.014	0.016	0.36	0.41	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.03	2.66	
P	-	0.050		1.27	
R	0.115		2.93		
v	0.135		3.43		

STYLE 1: PIN 1. ANODE

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